



IFW

# TRANSMITTAL OF FORMAL DRAWINGS

Docket No.  
FIS920030410US1

In Re Application Of: **Khater, et al.**

Serial No.	Filing Date	Confirmation No.	Examiner	Art Unit
10/709,222	4/22/04			

Invention: **Structure and Method of Forming Bipolar Transistor Having a Self-Aligned Raised Extrinsic Base Using a Link-Up Region Formed from an Opening**

Address to:  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Transmitted herewith are:

12 sheets of formal drawing(s) for this application.

☒ Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c).

  
Signature

H. Daniel Schnurmann  
Agent  
REGISTRATION NO.: 35,791

Dated: July 20, 2004

I certify that this document and attached formal drawings are being deposited on July 20, 2004 with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

  
Signature of Person Mailing Correspondence

**KAREN CINQ-MARS**

Typed or Printed Name of Person Mailing Correspondence